



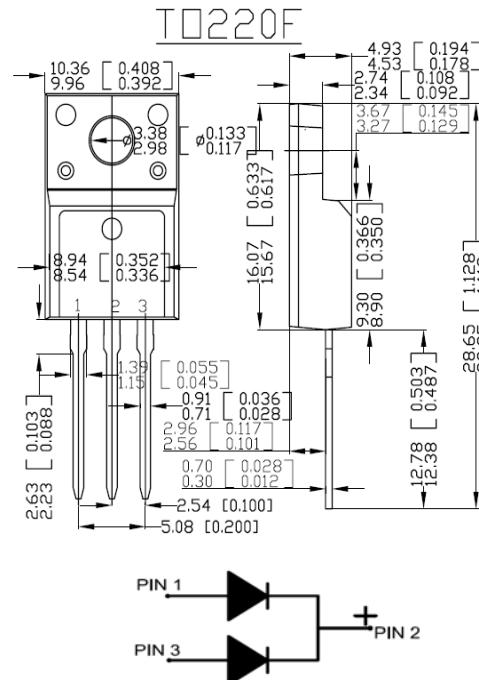
SHENZHEN HAOLIN ELECTRONICS TECHNOLOGY CO., LTD

## TO-220F SCHOTTKY BARRIER RECTIFIERS

## MBR10100CT

## FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



Dimensions in millimeters and (inches)

## ELECTRICAL CHARACTERISTICS (Tamb=25°C)

Characteristic	Symbol	MBR10100CT	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>		
Working Peak Reverse Voltage	V <sub>RWM</sub>	100	V
DC Blocking Voltage	V <sub>R</sub>		
Average Rectified Output Current	I <sub>c</sub>	10	A
Maximum Instantaneous Forward Voltage @ I <sub>F</sub> =10A, T <sub>c</sub> =25°C @ I <sub>F</sub> =10A, T <sub>c</sub> =125°C @ I <sub>F</sub> =20A, T <sub>c</sub> =25°C @ I <sub>F</sub> =20A, T <sub>c</sub> =125°C	V <sub>F</sub>	0.80 0.65 0.85 0.75	V
Peak Reverse Current @ T <sub>c</sub> =25°C at Rated DC Blocking Voltage @ T <sub>c</sub> =125°C	I <sub>R</sub>	10 100	uA
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	-55 to +150	°C

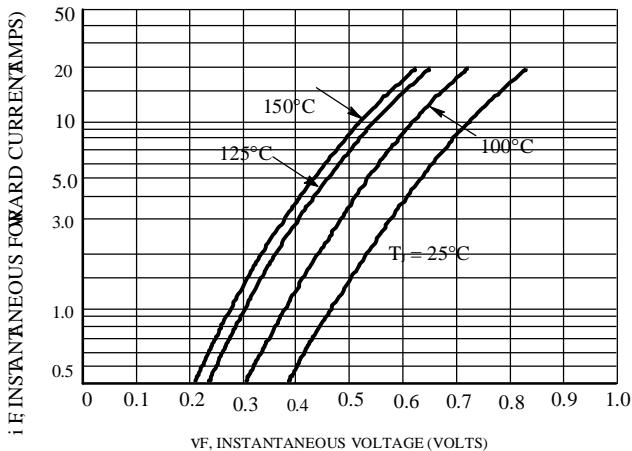


Figure 1. Typical Forward Voltage

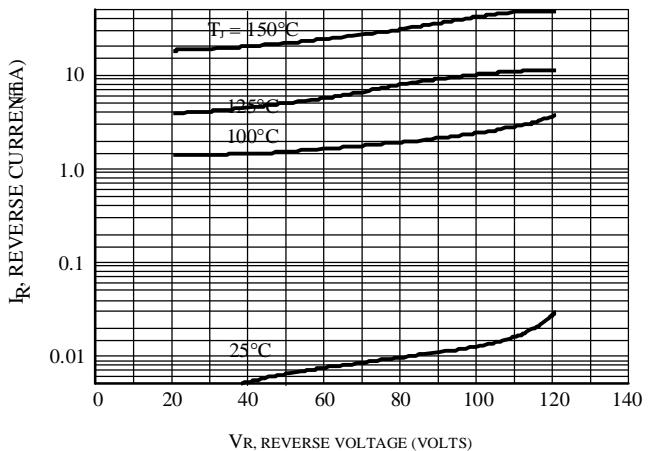


Figure 2. Typical Reverse Current

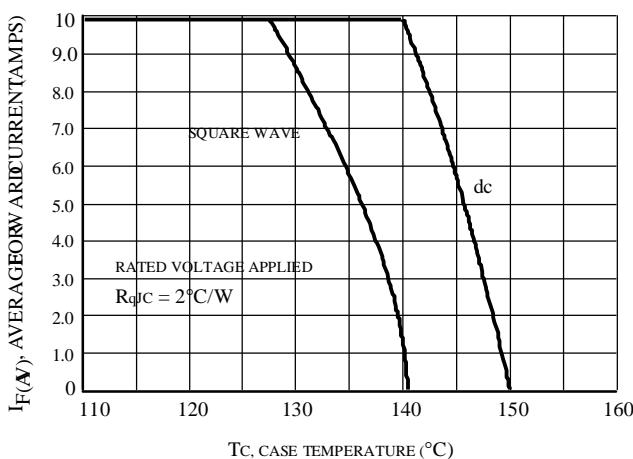


Figure 3. Current Derating, Case

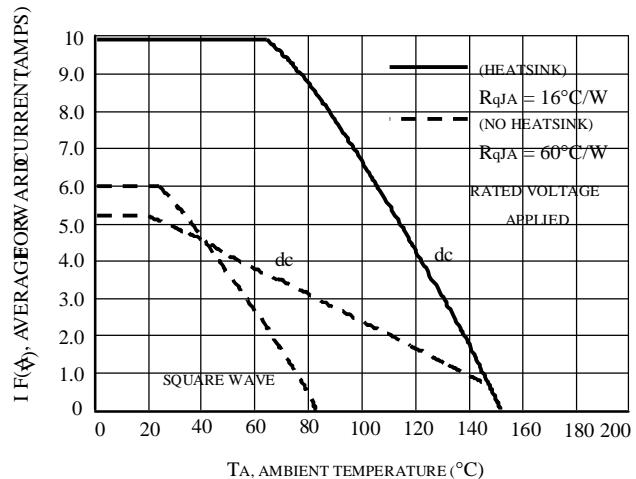


Figure 4. Current Derating, Ambient

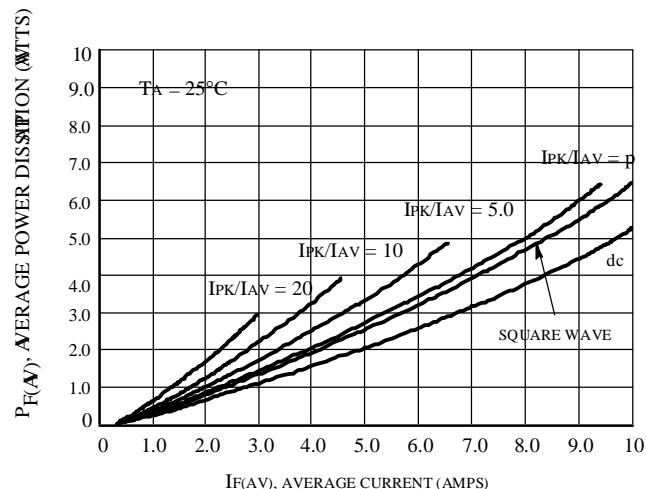


Figure 5. Forward Power Dissipation